



50 mA, 24 V, 3.2-µA Supply Current Low-Dropout Linear Regulator in SC70 Package

FEATURES

- Qualification in Accordance With AEC-Q100⁽¹⁾
- Qualified for Automotive Applications
- Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval
- 24-V Maximum Input Voltage
- Low 3.2-µA Quiescent Current at 50 mA
- Stable With Any Capacitor (> 0.47 µF)
- 50-mA Low-Dropout Regulator
- Available in 2.5 V, 3 V, 3.3 V, 5 V, and Adjustable (12 V to 15 V)
- Minimum/Maximum Specified Current Limit
- 5-Pin SC70/SOT-323 (DCK) Package
- -40°C to 125°C Specified Junction Temperature Range
 ⁽¹⁾Contact Texas Instruments for details. Q100 qualification data available on request.

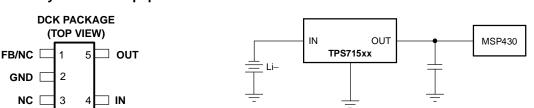
APPLICATIONS

- Ultra Low Power Microcontrollers
- Cellular/Cordless Handsets
- Portable/Battery-Powered Equipment

DESCRIPTION

The TPS715xx low-dropout (LDO) voltage regulators offer the benefits of high input voltage, low-dropout voltage, low-power operation, and miniaturized packaging. The devices, which operate over an input range of 2.5 V to 24 V, are stable with any capacitor (> 0.47 μ F). The low dropout voltage and low quiescent current allow operations at extremely low power levels. Therefore, the devices are ideal for powering battery management ICs. Specifically, since the devices are enabled as soon as the applied voltage reaches the minimum input voltage, the output is quickly available to power continuously operating battery charging ICs.

The usual PNP pass transistor has been replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the low dropout voltage, typically 415 mV at 50 mA of load current, is directly proportional to the load current. The low quiescent current (3.2 μ A typically) is stable over the entire range of output load current (0 mA to 50 mA).





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TPS71501-Q1 TPS71525-Q1, TPS71530-Q1 TPS71533-Q1, TPS71550-Q1

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ANS

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

SC70/SOT-323 (DCK)

TPS71501QDCKRQ1

	Tj	VOLTAGE	PACKAGE	PART NUMBER	SYMBOL				
		2.5 V	SC70/SOT-323 (DCK)	TPS71525QDCKRQ1	ANU				
		3 V	SC70/SOT-323 (DCK)	TPS71530QDCKRQ1	ANV				
	-40°C to 125°C	3.3 V	SC70/SOT-323 (DCK)	TPS71533QDCKRQ1	ANW				
		5 V	SC70/SOT-323 (DCK)	TPS71550QDCKRQ1	ANX				

AVAILABLE OPTIONS⁽¹⁾

(1) Contact Texas Instruments for other voltage options between 1.25 V and 5.85 V.

(Adjustable) 1.2 V-15 V

ABSOLUTE MAXIMUM RATINGS

over operating temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

	UNIT
V _{IN} range	-0.3 V to 24 V
Peak output current	Internally limited
ESD rating, HBM	2 kV
ESD rating, CDM	500 V
Continuous total power dissipation	See Dissipation Rating Table
Junction temperature range, T _J	-40°C to 150°C
Storage temperature range, T _{stg}	-65°C to 150°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

BOARD	PACKAGE	R _{θJC} °C/W	R _{θJA} °C/W	DERATING FACTOR ABOVE T _A = 25°C	T _A ≤ 25°C POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
Low-K ⁽¹⁾	DCK	165	395	2.52 mW/°C	250 mW	140 mW	100 mW
High-K ⁽²⁾	DCK	165	315	3.18 mW/°C	320 mW	175 mW	130 mW

(1) The JEDEC Low-K (1s) board design used to derive this data was a 3 inch x 3 inch, two-layer board with 2 ounce copper traces on top of the board.

(2) The JEDEC High-K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.



ELECTRICAL CHARACTERISTICS

over operating junction temperature range (T_J = -40°C to 125°C), $V_{IN} = V_{OUT(NOM)} + 1 V$, $I_{OUT} = 1 mA$, $C_{OUT} = 1 \mu F$ unless otherwise noted. Typical values are at $T_{J} = 25^{\circ}C$.

PA	RAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Lange transition of (1)		V	I _O = 10 mA	2.5		24	N/	
Input voltage ⁽¹⁾ V _{IN}			I _O = 50 mA	3		24	V	
V _{OUT} voltage rang	e (TPS71501)			1.2	1.2 15			
)/(1)		and T	V_{IN} + 1 V \leq V_{IN} \leq 24 V	-4%		. 40/		
V _{OUT} accuracy ⁽¹⁾	Over V _{IN} , I _{OL}	_{JT} , and T	$100 \ \mu A \le I_{OUT} \le 50 \ mA$	-4%	+4	+4%		
Ground pin curren	t	I _{GND}	$0 \text{ mA} \le I_{OUT} \le 50 \text{ mA}$ 3.2 1		12	μA		
Load regulation $\Delta V_{OUT} / \Delta I_{OUT}$			I _{OUT} = 100 μA to 50 mA		22		mV	
Output voltage Ine regulation (1) $\Delta V_{OUT} / \Delta V_{IN}$			V_{OUT} + 1 V < $V_{IN} \le 24$ V		20	60	mV	
Output noise voltage V _n		Vn	BW = 200 Hz to 100 kHz, C_{OUT} = 10 µF, I _{OUT} = 50 mA		575		μVrms	
Output current limit I _{CL}		I _{CL}	$V_{O} = 0 V$	125		750	mA	
Power-supply ripple rejection PSRR		PSRR	f = 100 kHz, C _{OUT} = 10 μF		60		dB	
$\label{eq:VIN} \begin{array}{ c c } \hline Dropout \ voltage \\ V_{IN} = V_{OUT(NOM)} \ - \ 1 \ V \end{array} \hspace{1.5cm} V_{DO}$		V _{DO}	I _{OUT} = 50 mA		415	750	mV	

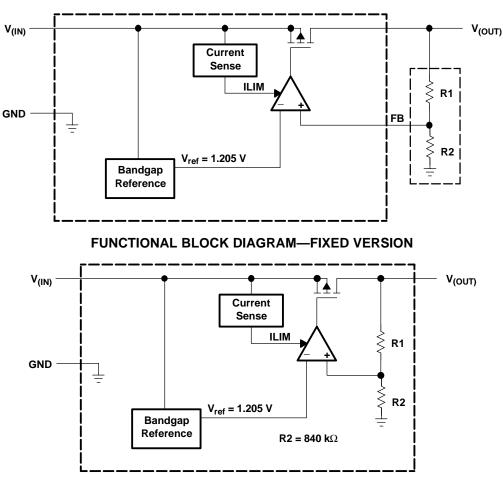
(1) Minimum $V_{IN} = V_{OUT} + V_{DO}$ or the value shown for *input voltage* in this table, whichever is greater.

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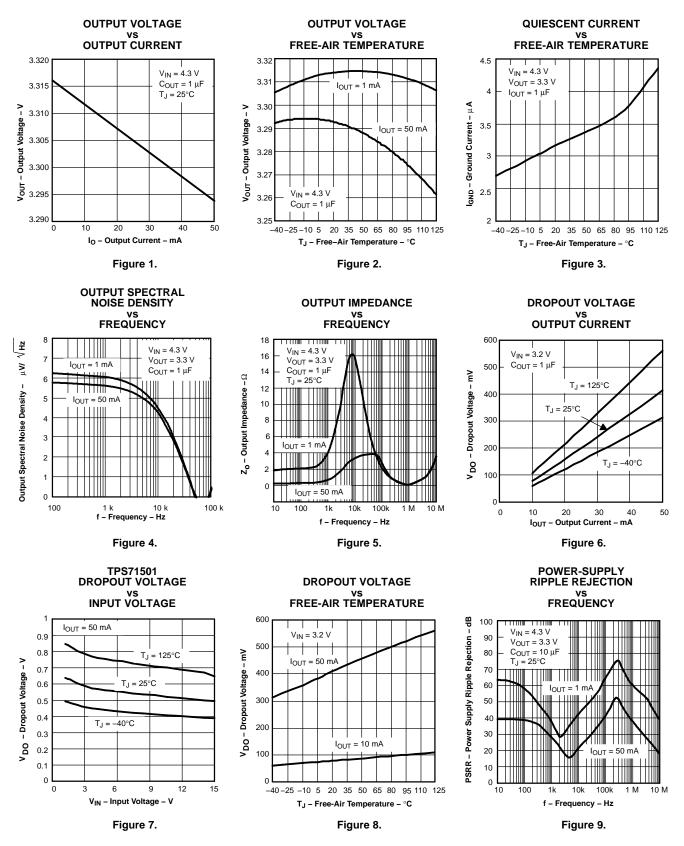
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TERMINAL			
NAME	N	0.	DESCRIPTION
INAIVIE	FIXED	ADJ.	
FB	1		Adjustable version. This terminal is used to set the output voltage.
NC	1		No connection
GND	2 2		Ground
NC	NC 3 3		No connection
IN 4 4		4	Unregulated input supply.
OUT	5	5	Output of the regulator, any output capacitor $\geq 0.47~\mu F$ can be used for stability.

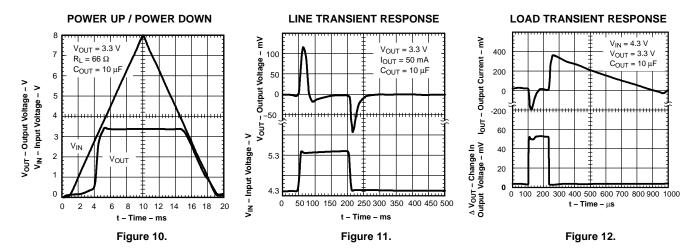
TYPICAL CHARACTERISTICS



TPS71501-Q1 TPS71525-Q1, TPS71530-Q1 TPS71533-Q1, TPS71550-Q1

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TYPICAL CHARACTERISTICS (continued)



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APPLICATION INFORMATION

The TPS715xx family of LDO regulators has been optimized for ultra-low power applications such as the MSP430 microcontroller. Its ultralow supply current maximizes efficiency at light loads and its high input voltage range makes it suitable for supplies such as unconditioned solar panels.

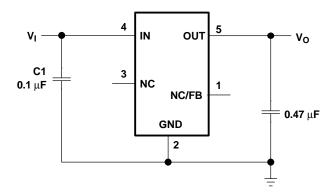


Figure 13. Typical Application Circuit (Fixed Voltage Version)

External Capacitor Requirements

Although not required, a 0.047-µF or larger input bypass capacitor, connected between IN and GND and located close to the device, is recommended to improve transient response and noise rejection of the power supply as a whole. A higher-value input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

The TPS715xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. Any capacitor (including ceramic and tantalum) $\ge 0.47 \ \mu$ F properly stabilizes this loop.

Power Dissipation and Junction Temperature

To ensure reliable operation, worst-case junction temperature should not exceed 125°C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$ and the actual dissipation, P_D , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{J}max - T_{A}}{R_{\theta JA}}$$

where:

- T_Jmax is the maximum allowable junction temperature
- R_{0,JA} is the thermal resistance junction-to-ambient for the package (see the Dissipation Ratings table)
- T_A is the ambient temperature

The regulator dissipation is calculated using:

$$\mathsf{P}_{\mathsf{D}} = \left(\mathsf{V}_{\mathsf{I}} - \mathsf{V}_{\mathsf{O}}\right) \times \mathsf{I}_{\mathsf{O}}$$

Power dissipation resulting from quiescent current is negligible.

Regulator Protection

The TPS715xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

(1)

(2)

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APPLICATION INFORMATION (continued)

The TPS715xx features internal current limiting. During normal operation, the TPS715xx limits output current to approximately 500 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. Take care not to exceed the power dissipation ratings of the package.

Programming the TPS71501 Adjustable LDO Regulator

The output voltage of the TPS71501 adjustable regulator is programmed using an external resistor divider as shown in Figure 14. The output voltage is calculated using:

$$V_{O} = V_{ref} \times \left(1 + \frac{R1}{R2}\right)$$

(3)

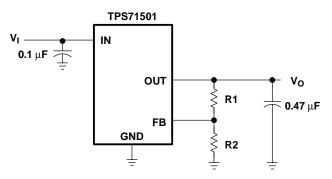
(4)

where:

• V_{REF} = 1.205 V typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately $1.5-\mu$ A divider current. Lower value resistors can be used for improved noise performance, but the solution consumes more power. Higher resistor values should be avoided as leakage current into/out of FB across R1/R2 creates an offset voltage that artificially increases/decreases the feedback voltage and thus erroneously decreases/increases V₀. The recommended design procedure is to choose R2 = 1 M Ω to set the divider current at 1.5 μ A and then calculate R1 using:

$$R1 = \left(\frac{V_{O}}{V_{ref}} - 1\right) \times R2$$



OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2
1.8 V	0.499 MΩ	1 MΩ
2.8 V	1.33 MΩ	1 MΩ
5.0 V	3.16 MΩ	1 MΩ

Figure 14. TPS71501 Adjustable LDO Regulator Programming

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS71501QDCKRQ1	ACTIVE	SC70	DCK	5	3000	TBD	CU NIPDAU	Level-1-260C-UNLIM
TPS71525QDCKRQ1	ACTIVE	SC70	DCK	5	3000	TBD	CU NIPDAU	Level-1-260C-UNLIM
TPS71533QDCKRQ1	ACTIVE	SC70	DCK	5	3000	TBD	CU NIPDAU	Level-1-260C-UNLIM
TPS71550QDCKRQ1	ACTIVE	SC70	DCK	5	3000	TBD	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

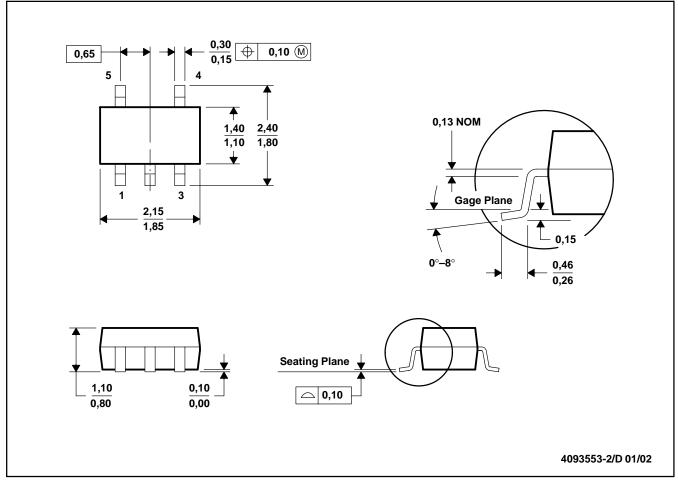
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DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-203



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